

Set: 2

① a) $V_G = 0$, $i_{DS} = 2 \text{ mA}$

b) $V_D = 5 - 2i_{DS} = 5 - 2 \times 2 = 5 - 4 = 1 \text{ V}$

Part-a

c) Let, ... saturation

$$i_{DS} = \frac{1}{2} K (V_{GS} - V_T)^2$$

$$\Rightarrow 2 = \frac{1}{2} \times 4 \times (V_{GS} - 1)^2$$

$$\Rightarrow (V_{GS} - 1)^2 = 1 \quad \because V_{OV} = 1 \text{ V}$$

$$\because V_{GS} = 2 \text{ V} \quad \Rightarrow V_G - V_S = 2 \text{ V}$$

$$\because V_S = -2 \text{ V}$$

Hence, $V_{DS} = V_D - V_S = 1 + 2 = 3 \text{ V} > V_{OV}$

\therefore assumption is correct.

Part-b

$f =$

$$\frac{A(B+C)D}{\dots}$$

② Part-a KVL: $1 - 40i_B - V_{BE} = 0$

Let, ... active.

$$\because V_{BE} = 0.7 \text{ V}$$

$$\therefore 1 - 40i_B - 0.7 = 0$$

$$\Rightarrow i_B = \frac{0.3}{40} = 0.0075 \text{ mA}$$

$$i_c = \beta i_B = 100 \times 0.0075 = 0.75 \text{ mA}$$

$$\therefore i_E = i_c + i_B = 0.7575 \text{ mA}$$

$$\text{Here, } V_c = 12 - 4i_c = 12 - 4 \times 0.75 \\ = 12 - 3 = 9 \text{ V}$$

$$\therefore V_{CE} = V_c - V_E = 9 - 0 = 9 \text{ V} > V_{CE \text{ sat}}$$

\therefore assumption is correct.

Part-b BJT will be active for the valid

$$\text{input range: } 0.7 < V_{in} < 0.7 + \frac{V_s - 0.2 R_i}{\beta R_L}$$

$$\text{or, } 0.7 < V_{in} < 1.65 + 0.7 = 2.35$$

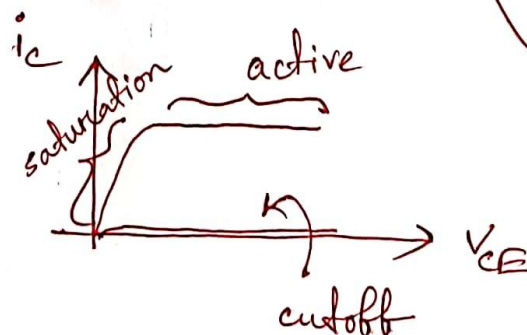
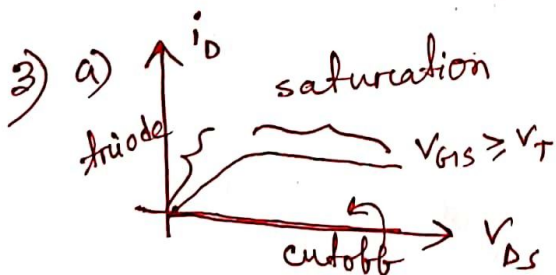
$$(i) \quad V_x = \frac{0.7 + \overset{2.35}{\cancel{1.65}}}{2} = 1.525 \text{ V}$$

$$V_Y = V_s + \frac{0.7 \beta R_L}{R_i} - \frac{\beta R_L}{R_i} V_x = 20 + 12 \times 0.7 - 12 \times \overset{1.525}{\cancel{1.65}} \\ = -10.1 \text{ V}$$

$$(ii) \quad K = -\frac{\beta R_L}{R_i} = -\frac{60 \times 2}{10} = -6 \times 2 = -12$$

swing

$$= 1.525 - 0.7$$



b)

$$c) \quad NM_0 = 3.5 - 1.5 = 2 \text{ V}$$

$$NM_1 = 5.5 - 4.7 = 0.8 \text{ V}$$

3 (b)

Assume the following values for the inverter circuit parameters: $V_S = 5\text{ V}$, $V_T = 1\text{ V}$, and $R_L = 10\text{ k}\Omega$. Assume, further, that $\frac{1}{k'_n V_{OV}} = 5$ for the MOSFET. Determine a $\frac{W}{L}$ sizing for the MOSFET so that the inverter gate output for a logical 0 is able to switch OFF the MOSFET of another inverter.

Solution:

$$\begin{aligned} V_S \frac{R_{ON}}{R_{ON} + R_L} &< V_T \\ \Rightarrow 5 \frac{R_{ON}}{R_{ON} + 10} &< 1 \\ \Rightarrow 5R_{ON} &< R_{ON} + 10 \\ \Rightarrow R_{ON} &< \frac{10}{4} = 2.5 \end{aligned}$$

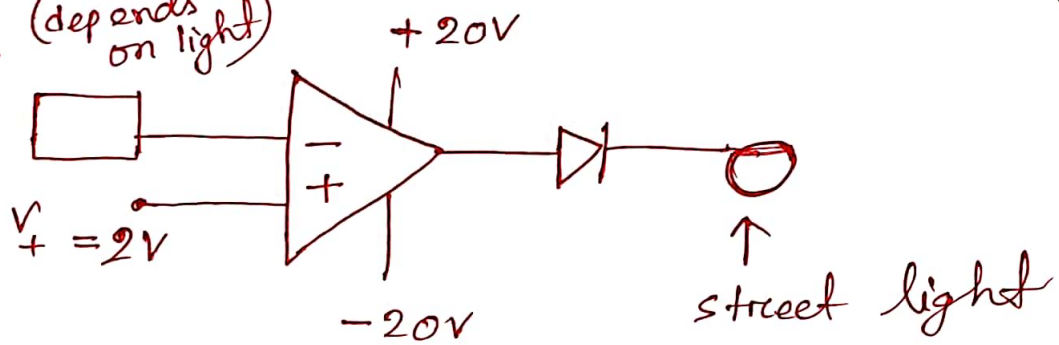
$$\text{Now, } R_{ON} = \frac{1}{k'_n \frac{W}{L} V_{OV}} = 5 \times \frac{1}{W/L}$$

$$\text{Hence } \frac{5}{W/L} < 2.5 \Rightarrow \frac{W}{L} > \frac{5}{2.5}$$

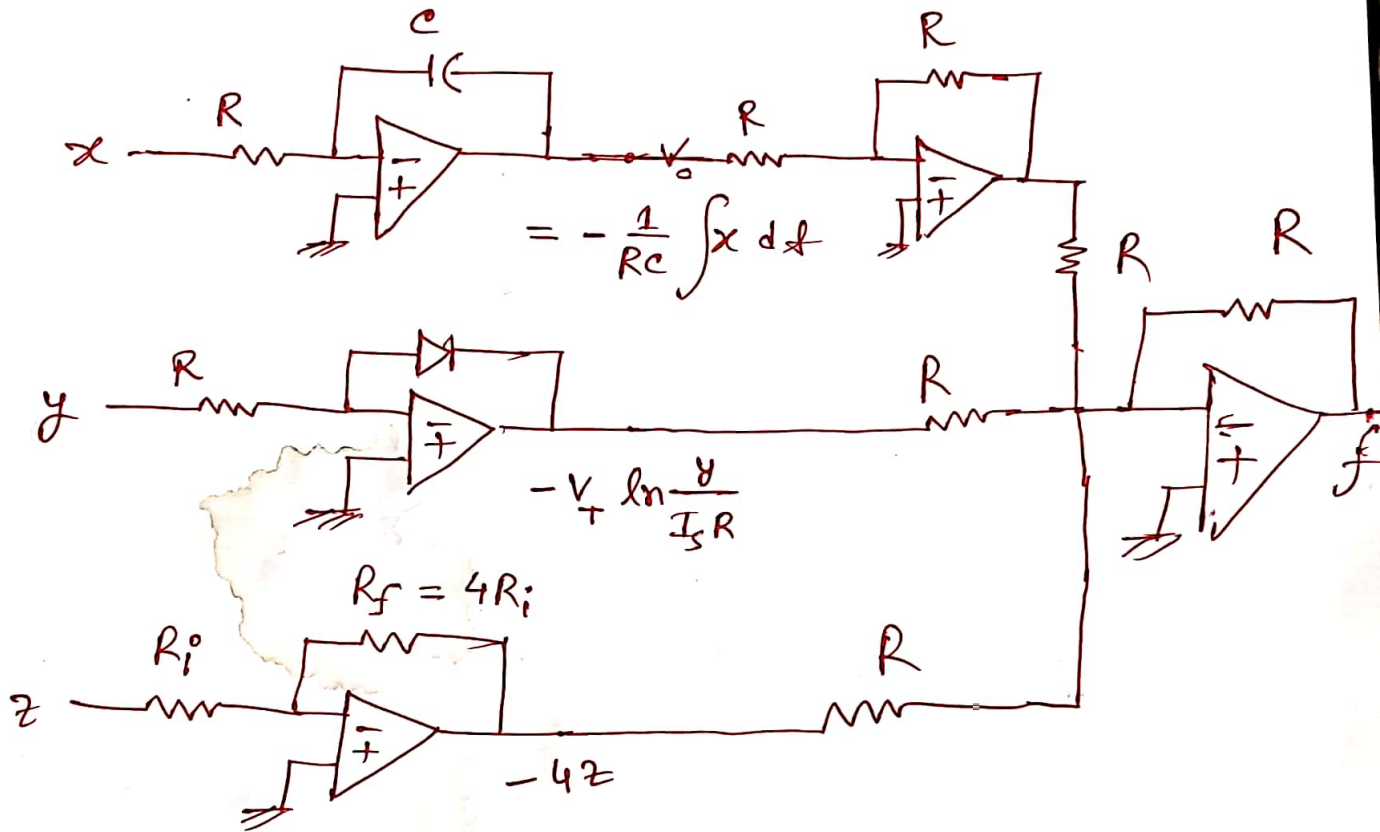
$$\Rightarrow \frac{W}{L} > 2$$

4)

a)

 V_- (depends on light)

b)



Here, $Rc = 2$, $I_S R = 1$, $V_T = 2$

c)

$$V_1 = -I_S R \exp\left(\frac{x}{V_T}\right)$$

$$y = -R_1 C_1 \frac{d}{dt} (V_1)$$

$$= -R_1 C_1 (-I_S R) \frac{d}{dt} (\exp(x)) \quad [V_T = 1]$$

$$= R_1 C_1 \exp(x) \quad [I_S R = 1]$$

Set-1

① a) $V_G = 0$, $i_{DS} = 4 \text{ mA}$, b) $V_D = 1 \text{ V}$

c) $V_{GS} = 1 + \sqrt{2} = 2.414 \text{ V}$

$[V_{ov} = 1.414 \text{ V}]$

$\therefore V_S = -2.414 \text{ V}$

$V_{DS} = 1 + 2.414 = 3.414 > V_{ov}$

$f = \overline{AB + CD}$

Part-b

② Part-a

$i_B = 0.006 \text{ mA}$

$i_C = \beta i_B = 0.6 \text{ mA}$

$i_E = 0.606 \text{ mA}$

$V_{CE} = V_C = 8 - 5i_C$
 $= 5 \text{ V} > V_{CEsat}$

Part-b

$0.7 < V_{in} < 1.8$

$V_X = 1.25 \text{ V}$

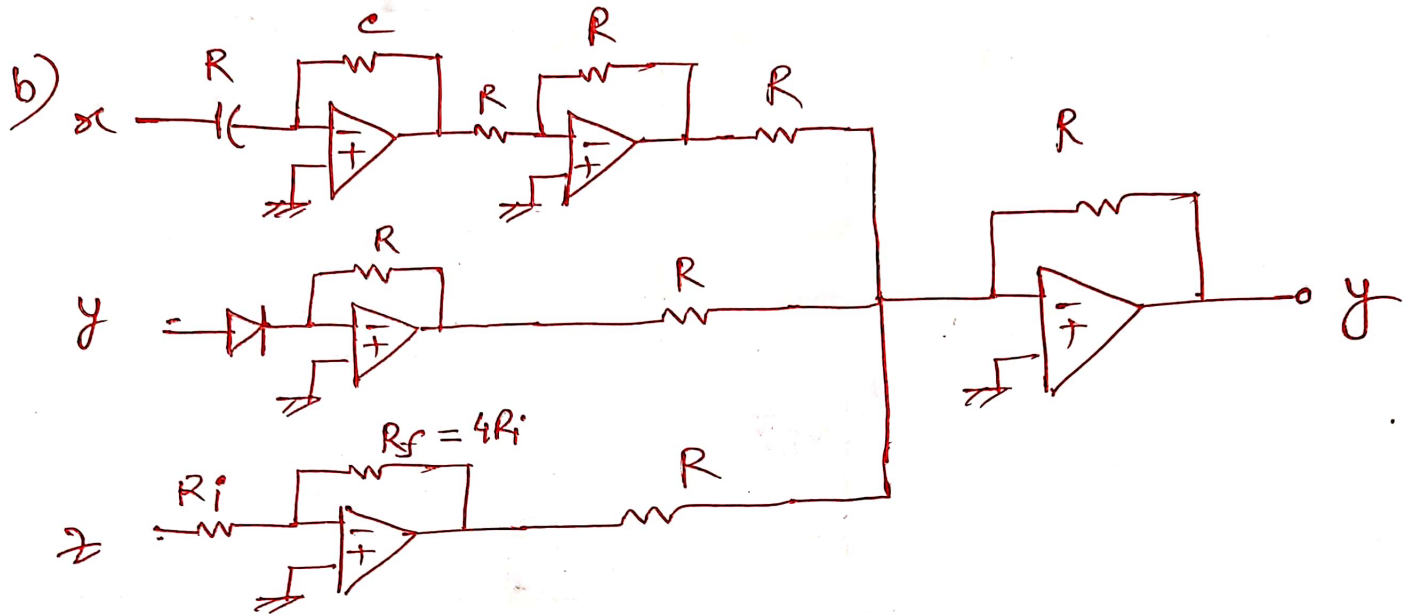
$V_Y = 10.1 \text{ V}$

③ maximum swing $= (1.25 - 0.7) = 0.55 \text{ V}$

④ $K = -\frac{\beta R_L}{R_F} = -\frac{120 \times 3}{20} = -18$

③ → same as set 2

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$$RC = 3, \quad V_T = 3$$

c) $y \neq \quad V_1 = -V_T \ln \frac{x}{I_S R}$

$$\begin{aligned} y &= -\frac{1}{RC} \int V_1 dt \\ &= -\frac{1}{RC} \int -V_T \ln \frac{x}{I_S R} dt \\ &= \frac{1}{RC} \int \ln x dt \end{aligned}$$

$$\left[V_T = 1, \quad I_S R = 1 \right]$$